



DMP3036SFVQ

30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	RDS(ON) Max	I _D Max Tc = +25°C
001/	20mΩ @ V _{GS} = -10V	004
-30V	29mΩ @ V _{GS} = -5V	-30A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

• General-purpose interfacing switches

Power management functions

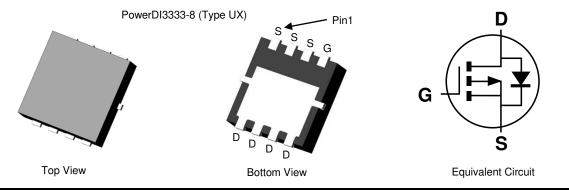
Features

- Low RDS(ON) Ensures On-State Losses Are Minimized
- Small Form-Factor, Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of The Board Area Occupied by SO-8, Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES[™] DMP3036SFVQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions

Mechanical Data

- Package: PowerDI®3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)



Ordering Information (Note 4)

Part Number	Pookogo	Pac	Packing		
Part Number	Package	Qty.	Carrier		
DMP3036SFVQ-7	PowerDI3333-8 (Type UX)	2,000	Tape & Reel		
DMP3036SFVQ-13	PowerDI3333-8 (Type UX)	3,000	Tape & Reel		

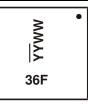
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



36F = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 22 = 2022) WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	-30	V
Gate-Source Voltage	VGSS	±25	V	
Continuous Drain Current, VGS = -10V (Note 6)	TA = +25°C TA = +70°C	lo	-8.7 -7.0	A
Continuous Drain Current, VGS = -10V (Note 7)	Tc = +25°C T _C = +70°C	lo	-30 -25	A
Maximum Continuous Body Diode Forward Current (Note 7)	ls	-3.6	A	
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	Ідм	-80	A	
Avalanche Current, L = 0.3mH (Note 8)	las	-17.5	А	
Avalanche Energy, L = 0.3mH (Note 8)		Eas	64	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	137	°C/W
Total Power Dissipation (Note 6)	·	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		RθJA	55	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	3.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	-30	—		V	$V_{GS} = 0V, I_{D} = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS		_	-1	μA	$V_{DS} = -30V$, $V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	-	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-	-2.5	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance			-	20	mΩ	$V_{GS} = -10V, I_{D} = -8A$	
	R _{DS(ON)}		_	29	11152	$V_{GS} = -5V, I_D = -5A$	
Diode Forward Voltage	Vsd	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		1931		pF	V _{DS} = -15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss		226	_			
Reverse Transfer Capacitance	Crss		168	_			
Gate Resistance	Rg		11	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = -5V)	Qg		8.8	_			
Total Gate Charge (V _{GS} = -10V)	Qg	_	16.5	_	nC	$V_{DS} = -15V, I_D = -10A$	
Gate-Source Charge	Qgs	_	2.6	_	no		
Gate-Drain Charge	Q _{gd}	_	3.6	_			
Turn-On Delay Time	tD(on)	_	8.2	_		$V_{DD} = -15V, V_{GS} = -10V, R_{GEN} = 3\Omega, I_D = -10A$	
Turn-On Rise Time	tR	_	14	_			
Turn-Off Delay Time	t _{D(off)}	_	65		ns		
Turn-Off Fall Time	tF	_	31.6	_]		
Reverse Recovery Time	trr	—	9.3		ns		
Reverse Recovery Charge	QRR	_	12.2	_	nC	$I_F = -8A$, di/dt = 500A/µs	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

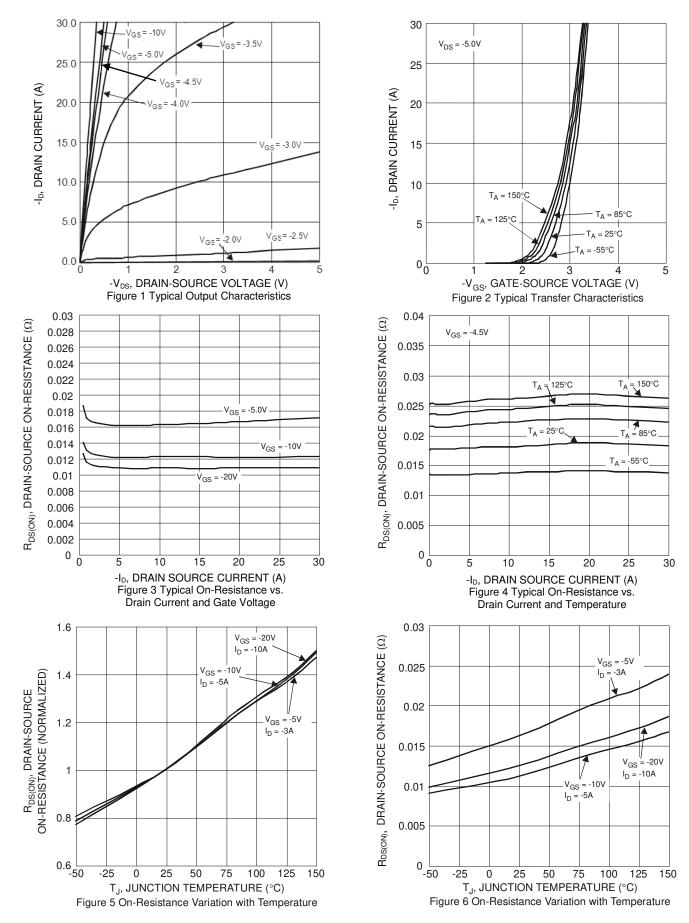
Device motified on FR-4 poblad, with minimum recommended pad layout, single store.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

9. Short duration pulse test used to minimize self-heating effect.

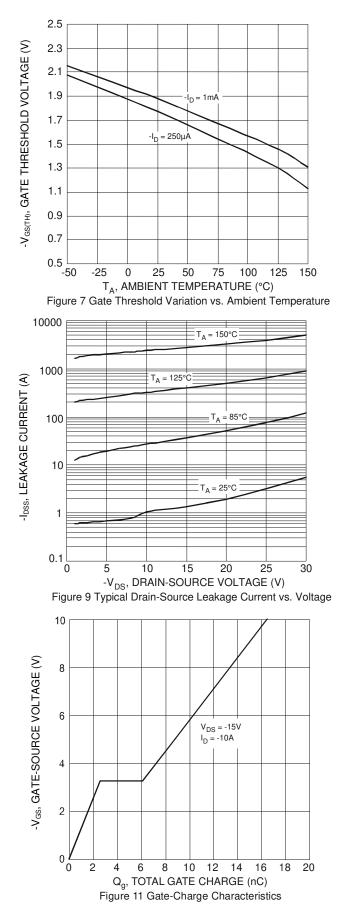
10. Guaranteed by design. Not subject to product testing.

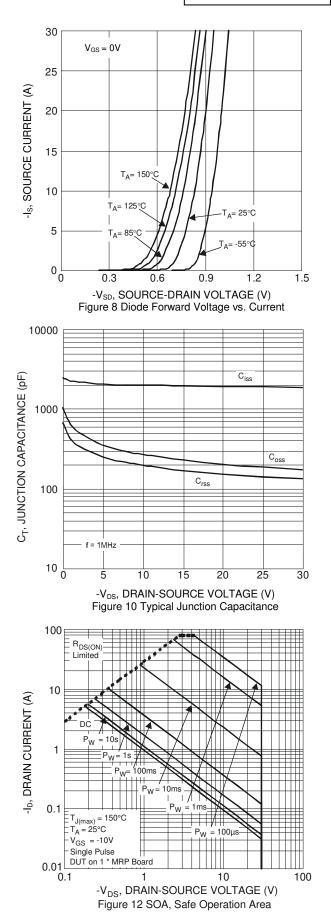






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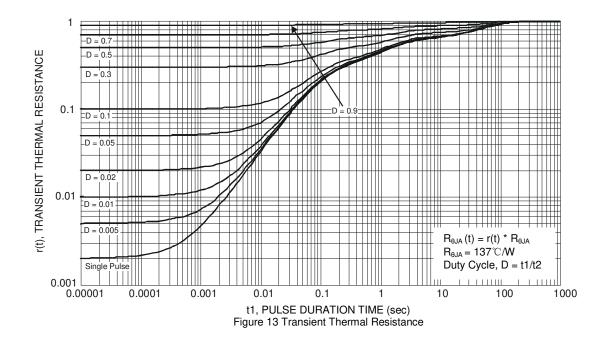




DMP3036SFVQ Document number: DS43979 Rev. 2 - 2 4 of 7 www.diodes.com



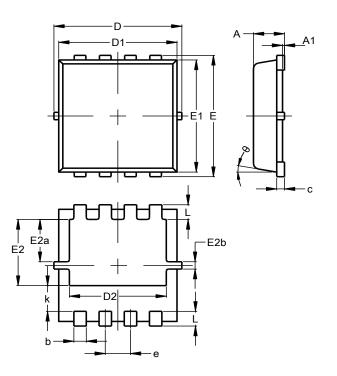






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



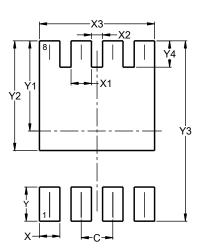
	PowerDI3333-8 (Type UX)					
Dim			Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
E	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E2a	0.95	1.35	1.15			
E2b	0.10	0.30	0.20			
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
X3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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